查询"2SA1203\_07"做蜿庵A Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1203

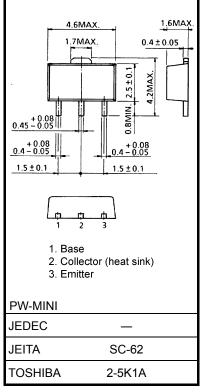
### **Audio Frequency Amplifier Applications**

Unit: mm

- Suitable for output stage of 3 watts amplifier
- Small flat package
- $P_C = 1.0$  to 2.0 W (mounted on a ceramic substrate)
- Complementary to 2SC2883

### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	$V_{CBO}$	-30	V	
Collector-emitter voltage	V <sub>CEO</sub>	-30	V	
Emitter-base voltage	V <sub>EBO</sub>	-5	V	
Collector current	IC	-1.5	Α	
Base current	ΙΒ	-0.3	Α	
Collector power dissipation	PC	500	mW	
	PC	1000		
	(Note 1)	1000		
Junction temperature	Tj	150	°C	
Storage temperature range	T <sub>stg</sub>	−55 to 150	°C	



Weight: 0.05 g (typ.)

Note 1: Mounted on a ceramic substrate (250 mm<sup>2</sup> × 0.8 t)

Note 2: Using continuously under heavy loads (e.g. the application of

high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

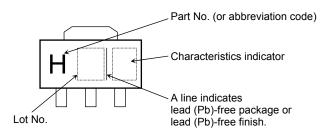
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# Energia Characteristics (Ta = 25°C)

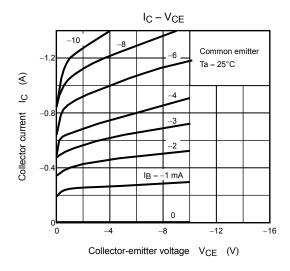
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -30 \text{ V}, I_{E} = 0$	_	_	-0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-0.1	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-30	_	_	V
Emitter-base breakdown voltage	V (BR) EBO	$I_E = -1 \text{ mA}, I_C = 0$	-5	_	_	٧
DC current gain	h <sub>FE</sub> (Note 3)	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -500 mA	100	_	320	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = -1.5 A, I <sub>B</sub> = -0.03 A	_	_	-2.0	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -500 mA	_	_	-1.0	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -500 mA	_	120	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	_	50	pF

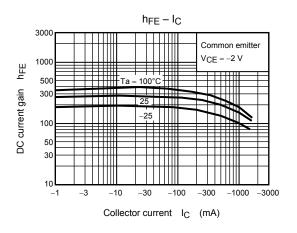
Note 3:  $h_{\text{FE}}$  classification O: 100 to 200, Y: 160 to 320

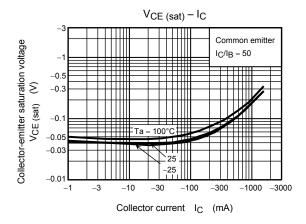
# Marking

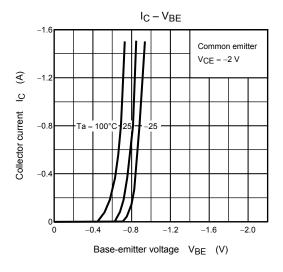


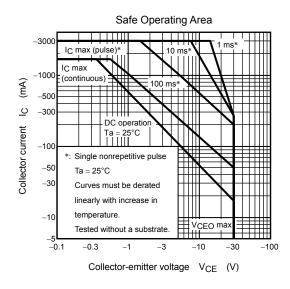
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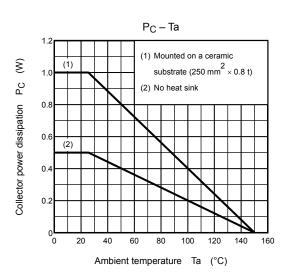












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